

CHCRUS

This is the accepted manuscript made available via CHORUS. The article has been published as:

Spin glass dynamics at the mesoscale

Samaresh Guchhait, Gregory G. Kenning, Raymond L. Orbach, and Gilberto F. Rodriguez Phys. Rev. B **91**, 014434 — Published 28 January 2015

DOI: 10.1103/PhysRevB.91.014434

Spin Glass Dynamics at the Mesoscale

Samaresh Guchhait¹, Gregory G. Kenning², Raymond L. Orbach³, and Gilberto F. Rodriguez⁴

¹Microelectronics Research Center, The University of Texas at Austin, Austin, Texas 78758

²Department of Physics, Indiana University of Pennsylvania, Indiana, Pennsylvania 15705

³ Texas Materials Institute, The University of Texas at Austin, Austin, Texas 78712 and

⁴Department of Physics, University of California, Riverside, California 92521

(Dated: January 9, 2015)

The mesoscale allows a new probe of spin glass dynamics. Because of the spin glasses lower critical dimension $d_l > 2$, the growth of the correlation length $\xi(t,T)$ can change the nature of the spin glass state at a crossover time t_{co} when $\xi(t_{co},T) = \ell$, a minimum characteristic sample length (i.e. film thickness for thin films and crystallite size for bulk samples). For thin films, and times $t < t_{co}$ such that $\xi(t,T) < \ell$, conventional three dimensional dynamics are observed. When $t > t_{\rm co}$, a crossover to d = 2 behavior takes place. The parallel correlation length, associated with a $T_g = 0$ transition, increases in time from the saturated value of the perpendicular correlation length ℓ to an equilibrium value of the parallel correlation length proportional to $T^{-\nu}$. This results in a pancake-like correlated state, with a thickness ℓ and a temperature dependent in-plane radius that increases with decreasing temperature. Activated dynamics are associated with these states. Measurements on Cu:Mn thin films are analyzed quantitatively within this framework. We extract a temperature dependent activation energy from a fit to the frequency dependence of the dynamic susceptibility. The extrapolated temperature at which the activation energy would become large is close to the extrapolated glass transition temperature from ac susceptibility measurements. All known relevant experimental data are consistent with this approach. For polycrystalline materials, there is a distribution of length scales $\mathcal{P}(\ell)$. For sufficiently broad distributions, a logarithmic time dependence is derived for the time decay of the thermoremanent magnetization $M_{\text{TRM}}(t,T)$ using an approach originally derived by Ma. Properties dependent upon an effective waiting time t_w^{eff} are derived that are consistent with experiment, and further measurements are suggested.

PACS numbers: 71.23.Cq, 75.10.Nr, 75.40.Gb, 75.50.Lk

I. INTRODUCTION

The time evolution of non-linear dynamical systems depend strongly on initial conditions. For spin glasses, Zotev *et al.* [1] showed that the aging properties of a spin-glass depend sensitively on the cooling protocol associated with arrival at the final measurement temperature. This behavior was explored at some length in the work of Rodriguez *et al.* [2]. They demonstrated the relationship between the cooling protocol and an effective waiting time t_w^{eff} .

Another initial condition to which attention has been drawn [3,4] is the relation of the magnitude of the spin glass correlation length $\xi(t,T)$ to a representative sample dimension, ℓ . In a physical system prepared at times sufficiently short so that $\xi(t,T) < \ell$, the system behaves according to (spatial) dimension d = 3 dynamics. However, for preparation times greater than a crossover time $t_{\rm co}$, defined through $\xi(t_{\rm co},T) = \ell$, the effective dimensionality is reduced. This reduction is of great significance for spin glasses in that the lower critical dimension $d_l > 2$ [5,6].

The advent of the mesoscale [7] allows these properties to be probed in real systems, allowing in principle the determination of the transverse correlation length exponent ν . This paper will be concerned with thin films, of the order of 20 - 30 Å thickness, and polycrystalline samples where the crystallite size is in the mesoscale range. The experimental results for thin films form a remarkable series of papers, beginning with the Michigan State University group [8, 9] and culminating with their collaborators at Uppsala University [10, 11]. Though these papers are now nearly twenty five years old, they nevertheless hold promise for new studies that will further elucidate spin glass dynamics in reduced dimensionality. The results for polycrystalline materials are more recent, and illustrate the origin of the "end of aging" dynamically.

Our analysis is based on theoretical calculations [12 - 14] for the growth of the spin glass correlation length with time, $\xi(t,T)$, and its experimental observation [15] for d = 3. In d = 2, the parallel (in plane) spin glass correlation length grows rather slowly with time as calculated by Rieger *et al.* [16], then saturates at an equilibrium value proportional to $T^{-\nu}$ with the exponent $\nu = 3.6 \pm 0.02$ for Ising spin glasses [17], and $\nu = 0.9 \pm 0.2$ for Heisenberg spin glasses [18].

For short measurement times, the spin glass correlation length $\xi(t,T)$ is less than the film thickness, and the dynamics can be regarded as appropriate to d = 3. Under these conditions, it is found [12 - 14] that $\xi(t,T)$ grows as,

$$\frac{\xi(t,T)}{a_0} = c_1 \left(\frac{t}{\tau_0}\right)^{c_2 \cdot (T/T_g)},\tag{1}$$

where a_0 is the average distance between magnetic spins, c_1 and c_2 are material-dependent constants, T_g is the spin glass transition temperature, and τ_0 is the average

temperature, $\xi(t, T_q)$ grows with time until $t = t_{co}$ when $\xi(t_{co}, T_q) = \ell$, the sample thickness. After t_{co} , the system is frozen in a d = 2 state, with the largest barrier set

entirely by the sample's physical dimensions,

$$\frac{\Delta_{\max}(T=T_q)}{k_B T_g} = \frac{1}{c_2} \left[\ln\left(\frac{\ell}{a_0}\right) - \ln c_1 \right], \qquad (4)$$

with both perpendicular and parallel correlation lengths $\xi^{\perp}(t \geq t_{\rm co}, T_q) = \xi^{\parallel}(t \geq t_{\rm co}, T_q) = \ell$. The only role of the quench temperature T_q is the rate at which $\xi(t, T_q)$ grows to ℓ from Eq. (1). The fact that Eq. (4) holds for different T_q arises from the self-similarity of states at different temperatures, found experimentally over accessible temperature ranges in Refs. [4] and [20].

When the temperature is lowered from T_q , $\xi^{\parallel}(t,T)$ grows to $\xi^{\parallel}_{eq}(T)$, proportional to $T^{-\nu}$. This leads to,

$$\xi^{\text{eff}}(t_{\text{co}}, T) = \left\{ \ell \cdot [\xi_{\text{eq}}^{\parallel}(T)]^2 \right\}^{\frac{1}{3}},$$
 (5)

and, concomitantly, through Eq. (2),

$$\frac{\Delta_{\max}(T)}{k_B T_g} = \frac{1}{c_2} \left[\ln \left(\frac{\xi^{\text{eff}}(t_{\text{co}}, T)}{a_0} \right) - \ln c_1 \right].$$
(6)

The combination of a maximum barrier height and exponential increase of the state occupancy with Hamming distance (and hence barrier height [22]) means that the dynamics after $t_{\rm co}$ will be Arrhenius-like, with an exponent $\Delta_{\rm max}(T)$ that is itself temperature dependent.

The temperature dependence of $\Delta_{\max}(T)$ has a component in addition to the temperature dependence of ξ_{eq}^{\parallel} . This arises from the temperature dependence of the Hamming distance arising from the ultrametric tree for the free energy states, associated with the temperature dependence of the Edward-Anderson overlap $q_{EA}(T)$ [15]. This has been measured explicitly through the temperature cycling experiments of Joh *et al.* [15]. In Sec. III of this paper, we shall assume that the increase in Hamming distance is associated with the correlation length $\xi^{\text{eff}}(t_{\text{co}}, T)$ through Eq. (5). A new interpretation of the experiments of Kenning *et al.* [8, 9] and Sandlund *et al.* [10] and Granberg *et al.* [11] on thin Cu:Mn films will be based on this analysis.

In the latter two papers, the dynamic susceptibility $\chi(\tau)$ was measured at different observations times τ $(\tau = 1/\omega)$ for thin film sandwiches of Cu:Mn 13.5 at.%, of thickness 30 Å and 20 Å, respectively, over a range of temperatures from the bulk value of the spin glass temperature T_g to low temperatures. The authors extrapolated the effective spin glass transition temperature $T_g^{\text{eff}} \rightarrow 0$ as the film thicknesses were reduced. What is new in our analysis is the interpretation that what was observed was the response of the correlated spins within an effective volume $[\xi^{\text{eff}}(t_{\text{co}}, T)]^3$ through the arguments leading up to Eqs. (5) and (6).

This picture was invoked in a previous publication [4] to explain the time dependence of zero-field cooled magnetization (ZFC) of (thicker) film of a-Ge:Mn [23], but

exchange time $\tau_0 \approx \hbar/(k_B T_g)$. The exponent c_2 is found to be very small, of the order of $0.12 < c_2 < 0.17$, depending upon the system [3]. As a consequence, $\xi(t,T)$ increases very slowly at long times, but it can reach thin film thicknesses within experimental time scales provided the temperature T is not too far below the glass temperature T_g . Thus, as we shall show, the growth of $\xi(t,T)$ to a film thickness $\ell = 15.5$ nm (the length scale of Guchhait *et al.* [4]) for Cu:Mn (13.5 at.%) takes 5×10^5 sec at $T = 0.83 T_g$, and the age of the universe for $T = 0.5 T_g$; while it takes only 5 msec for $\ell = 3$ nm (the length scale of Sandlund *et al.* [10]) at $T = 0.56 T_g$.

At a given temperature, the d = 3 correlation length $\xi(t,T)$ grows to the film thickness ℓ at a time we designate as the crossover time $t_{\rm co}$, changing the dimension from d = 3 to d = 2. At that point in time, the d = 2 parallel correlation length, $\xi^{\parallel}(t_{\rm co},T)$, equals the perpendicular correlation length $\xi^{\perp}(t_{\rm co},T) = \ell$ [19]. If the temperature is subsequently lowered, $\xi^{\perp}(t,T)$ is fixed at ℓ while the parallel (d = 2) correlation length grows slowly [16] until it reaches its equilibrium value $\xi^{\parallel}_{\rm eq}(T) \propto T^{-\nu}$.

The number of correlated spins, encompassed by the perpendicular and parallel correlation lengths, $\xi^{\perp}(t,T)$ and $\xi^{\parallel}(t,T)$, respectively, generates a distribution of free energy barrier heights as a function of the Hamming distance between states, up to a maximum $\Delta_{\max}(T)$ [3]. As shown in [20], the ultrametric relationship between states [21] separated by the barriers results in a temperature dependence for the barrier heights that causes a rapid growth (or diminution) as the temperature is lowered (or raised). Hence, in experiments where the temperature is changed during the experimental protocol, the initial temperature controls the subsequent dynamics. We term this temperature the "quench temperature", T_q .

Because the states are ultrametrically related, with state density increasing exponentially with increasing Hamming distance, the maximum barrier height reached after time t at temperature T, $\Delta_{\max}(t,T)$, effectively controls the dynamics [4, 20]. We relate $\Delta_{\max}(T)$ to $\xi(T)$ in analogy to d = 3 [15] through,

$$\frac{\Delta_{\max}(T)}{k_B T_g} = \frac{1}{c_2} \left[\ln \left(\frac{\xi(t,T)}{a_0} \right) - \ln c_1 \right].$$
(2)

In order to compare seamlessly with expressions appropriate to three dimensions, we define an effective correlation length $\xi^{\text{eff}}(t,T)$ for thin films by,

$$\xi^{\text{eff}}(t,T) = \left\{ \xi^{\perp}(t,T) \cdot [\xi^{\parallel}(t,T)]^2 \right\}^{\frac{1}{3}}.$$
 (3)

The d = 2 correlation length, $\xi^{\parallel}(t,T)$, is presumed to grow on the time scale of experiment to its equilibrium value $\xi^{\parallel}_{eq}(T)$, so that for $t \ge t_{co}$, $\xi^{eff}(t \ge t_{co}, T) \equiv \xi^{eff}(T)$ is only a function of temperature T, remembering, of course, that $\xi^{\parallel}_{eq}(T)$ remains temperature dependent, proportional to $T^{-\nu}$.

Under controlled experimental conditions, the temperature is quenched to an initial value, T_q . At that initial at the quench temperature T_q . This paper extends their treatment to (thinner) films of Cu:Mn [8 - 11], and to temperatures below and above T_q .

For polycrystalline spin glasses with random crystallite length scales, we shall argue that the RKKY exchange coupling is cut off by finite crystallite length scales. This occurs even though the electrical conductivity generally is somewhat insensitive to polycrystallinity. The reason lies in the nature of the RKKY interaction itself. Its long range and oscillatory nature is associated with the sharpness of the Fermi surface. However, as Kasuya calculates [24], electron scattering will change the long range $\cos(2k_F r_{ij})/[k_F r_{ij}]^3$ range dependence to $r_0/[(r_0^2 - r_{ij}^2)^2 + 4r_0^2 r_{ij}^2]$, where k_F is the Fermi wave vector, m_{ij} is the distance between tor, r_{ij} is the distance between spins i and j, and r_0 is a characteristic scattering length that we take to be of the order of the crystallite size. The lack of an oscillatory character removes *frustration*, a requirement for spin glass behavior (in addition to randomness), and thus effectively decouples the individual spin glass grains.

In analogy with the previous discussion, this will limit the growth of $\xi(t, T)$ to a size characteristic of a particular spin glass crystallite. The distribution of crystallite sizes leads to a distribution of maximum barrier heights Δ_{\max} according to (4). The overall dynamics for a distribution of activation energies can be calculated using an expression originally introduced by Ma [25], and more generally by Amir *et al.* [26]. One finds a long time logarithmic decay for the thermoremanent magnetization $M_{\text{TRM}}(t, T)$, first observed for spin glasses by Kenning *et al.* [27], but known for many other glassy systems [e.g. 28, 29]. In addition, this model can be used to explain the very large times for overlap of the $M_{\text{TRM}}(t,T)$ decay curves at increasing effective waiting times, t_w^{eff} , and the dependence of the crossover time, t_{co} on t_w^{eff} , as observed in [27].

The next section will be a brief review of the dynamical spin glass properties to be explored in the paper in order to give the reader not familiar with spin glass notation sufficient background to access subsequent sections. Sec. III will treat the dynamics of uniform spin glass thin films, showing that the crossover to d = 2 behavior leads to activated dynamics with a temperature dependent maximum barrier height as discussed above. Sec. IV addresses polycrystalline samples for random crystallite length scales, spanning a sufficiently broad range for the analysis of Ma [25] and Amir et al. [26] to be relevant. A logarithmic time decay for $M_{\text{TRM}}(t,T)$ is obtained, in agreement with the experiments of Ref. [27]. Sec. V analyzes the overlap of the very long time behavior of $M_{\text{TRM}}(t,T)$ for different t_w^{eff} , and Sec. VI the dependence of t_{co} on t_w^{eff} . Sec. VII summarizes our results followed by our many acknowledgments in Sec. VIII.

II. BRIEF REVIEW OF DYNAMICAL SPIN GLASS PROPERTIES

The memory effect, typical of glasses in general, and of spin glasses in particular, arises from the cooling of the sample temperature from above the freezing temperature, referred to as the spin glass temperature T_g , to the measurement temperature T_q (which is here same as the quench temperature as defined before). It is assumed that the time to reach T_q is short, (but see [2, 30] for discussions of the effect of the cooling protocol). The time spent at T_q before the magnetic field H is changed is termed the waiting time t_w . The magnetic field change, either from H = 0 to the applied field H, leading to zero-field cooled (ZFC) dynamics; or from the applied field H to H = 0, leading to thermore manent magnetization (TRM) dynamics; causes a change in the magnetic moment, the magnitude and time dependence of which depends upon t_w . The system exhibits, almost always, behavior characterized by an effective waiting time, t_w^{eff} , larger than t_w , depending upon the cooling protocol [2, 30]. The effective waiting time, t_w^{eff} , is typically extracted from the position of the peak in the relaxation function

$$S(t) = -\frac{1}{H} \frac{dM(t,T)}{d\ln t},$$
(7)

where M(t,T) is either the ZFC or TRM magnetization [31].

A physical interpretation of this phenomenon was introduced in Ref. [20] in terms of barrier hopping between degenerate free energy phase space states. The temperature dependence of a specific barrier was measured, and shown to increase rapidly as the temperature is lowered within a narrow temperature range of $\Delta T \approx 0.08$ K for Ag:Mn (2.6 at. %). For temperatures above T_q within this narrow temperature range, $T_q + \Delta T > T > T_q$, small increases in temperature reduce barrier heights significantly, allowing diffusion to proceed more rapidly between states representative of those present at the measuring temperature T_q . Hence, this effective aging time, t_w^{eff} , as derived from the peak position of S(t), is larger than the actual waiting time t_w , the longer the cooling protocol finds itself within the narrow temperature range.

The work of Rodriguez et al. [2,] and Parker et al. [30], examined the dependence of t_w^{eff} on the cooling path taken to reach T_q for Cu:Mn (6 at. %) ("Heisenberglike"); and CdCr_{1.7}In_{0.3}S₄, Au:Fe (8 at. %), and Fe_{0.5}Mn_{0.5}TiO₃ (all "Ising-like"), respectively. While their interpretations are different, they provided clear evidence that the cooling path to reach T_q alters the magnitude of t_w^{eff} , even for $t_w = 0$. For this reason, the experiments of Kenning et al. [27] were conducted using the fast cooling protocols of Ref. [2], where the temperature after the quench is not allowed to rise above T_q . This keeps the occupied phase space states within the same set of barriers appropriate to the effective aging time t_w^{eff} at T_q , or, equivalently, within the same spatial region spanned by $\xi(t_w^{eff}, T_q)$, minimizing t_w^{eff} for a given t_w . Using this protocol, one can safely work at longer times $t \gg t_w^{eff}$ to explore the consequences of $\xi(t,T)$ growing to sample dimensions. The end of aging is then associated with $\xi(t,T_q) \approx \ell$ at a fixed temperature T_q less than T_g at macroscopic length scales.

However, for mesoscopic length scales the form of Eq. (1) changes the growth dynamics. Thus, for $\ell \sim 3$ nm, as in the work of Sandlund *et al.* [10], $\xi(t,T_q) = \ell$ at 5 ms for $T_q = 37.5$ K ($T_g = 66.8$ K). This results in dynamics accessible within laboratory time scales, as will be discussed in the following section.

It is also important to understand the remarkable dependence of the growth rate of $\xi(t,T)$ on temperature from Eq. (1). Using the values for c_1 and c_2 from the literature [4, 20], one finds that $\xi(t, T)$ grows very slowly for T significantly less than T_g , while for temperatures in the vicinity of T_g the growth is relatively rapid. Thus, as long as the temperature is significantly below T_a , $\xi(t,T)$ will never reach ℓ on laboratory time scales, and spin glass dynamics are appropriate to d = 3. However, in the vicinity of T_q , the reverse is true. For example, Ref. [4] finds $\xi(t,T) = \ell$ on laboratory time scales for $15.5~\mathrm{nm}$ films of a morphous Ge:Mn in the narrow temperature range $0.83 < T/T_g < 0.92$ ($T_g = 24$ K). For $T < 20 \text{ K} (T/T_g = 0.83)$, the time required for $\xi(t, T) = \ell$ exceeds 4×10^5 sec (reaching 3×10^6 sec at 19 K, with $T/T_g = 0.79$), while for T > 22 K $(T/T_g = 0.92)$, the time for $\xi(t,T)$ to reach ℓ is of the order of 10^4 sec, a more accessible experimental time range. This limits dynamical measurement in practice to a rather narrow temperature range.

In summary, in order to prepare the spin glass sample for the purposes of extraction of dynamics in the time range where $\xi(t,T) \approx \ell$, it is necessary to work with as short a t_w^{eff} as possible, requiring a rapid cooling protocol wherein the approach of temperature to the measuring temperature T_q never rises above T_q after quench, and either select a narrow temperature range below T_g for which $\xi(t,T_q)$ can approach ℓ for macroscopic samples, or work with materials of mesoscale dimensions for which $\xi(t,T_q)$ can approach ℓ over a wide temperature range.

III. SPIN GLASS DYNAMICS FOR UNIFORM THIN FILMS

As discussed in Ref. [4], when the spin glass correlation length, $\xi(t,T)$, grows from nucleation at t = 0 to the thickness ℓ of a uniform thin film at $t = t_{\rm co}$, the system crosses over from dimension d = 3 to d = 2 dynamical behavior. The latter is associated with a bulk $T_g = 0$ by virtue of the lower critical dimension for spin glasses $d_l > 2$ [5, 6].

The earliest work on finite size effects on the spin glass transition were performed on thin films of Cu:Mn (7 at. %) at a single effective time scale (inversely proportional to the temperature scan rate) in Refs. [8, 9]. In that work, the spin glass thickness was changed in

order to change the spatial dimension from d = 3 to d = 2 in order to probe the spin glass lower critical dimension d_l . The spin glass transition temperature T_q was measured over a range of thicknesses, ranging from 2 nm to 1000 nm. Extrapolations were introduced in order to demonstrate that $T_q \rightarrow 0$ as one approached d = 2. In subsequent work, a broad spectrum of observation times τ was extracted for 30 Å thin films of Cu:Mn (13.5 at. %) from the dynamic susceptibility $\chi(\tau)$ measured as a function of temperature at frequencies $\omega = 1/\tau$ for $10^{-5} < \tau < 10^4$ sec in Ref. [10]; while thin films of thickness 20 Å were probed over time scales of $10^{-4} < \tau < 10^3$ sec in Ref. [11] in a similar manner. A generalized Arrhenius law with a zero-temperature critical point was extracted for the very thin films. This was interpreted in terms of "...a crossover from threeto two-dimensional spin-glass dynamics when one spatial dimension is gradually diminished to a finite size" [11].

However, as noted in Ref. [4], for times $t > t_{\rm co}$ (when the transition from d = 3 to d = 2 dynamics has taken place) there will still remain correlated spins in the spin glass state, different from the interpretation of [8, 9] and [10, 11]. There will exist a maximum barrier height between metastable states for these states, the largest of which is given by Eq. (4) while at the quench temperature T_q . Because the degeneracy of the ultrametric space increases exponentially with Hamming distance, and because the barrier heights Δ are linearly proportional to the Hamming distance [22], dynamical properties will be determined through the largest barrier height $\Delta_{\rm max}$ given by Eq. (4). This description remains until an external parameter is changed (e.g. temperature or magnetic field).

The data of Sandlund *et al.* [10] and Granberg *et al.* [11] for $\chi(\tau)$ versus temperature at different observation times τ allow a determination of the temperature dependence of $\Delta_{\max}(T)$. In d = 3, the temperature dependence of a specific barrier can be determined [20], with $\Delta_{\max}(T)$ increasing rapidly as the temperature is lowered from the quench temperature, as discussed in the Introduction. A fit to the measured data, when extrapolated to lower temperatures, produced very large values of $\Delta_{\max}(T)$ that were well outside the experimentally accessible time window. This was speculated to lead to the *pure* states of Parisi [32]. For d = 2, we shall show from the data of Ref. [10] that the correlated states also exhibit rapid barrier height growth as the temperature is lowered from the quench temperature T_q .

For temperatures accessed below the quench temperature, the increase of $\Delta_{\max}(T)$ with decreasing temperature arises from two sources for thin films, as discussed in the Introduction. The first is associated with the growth of the Hamming distance as the temperature is lowered. The second is the growth in real space of the parallel correlation length $\xi^{\parallel}(t,T)$. This length grows slowly in time [16] from an initial value of $\xi^{\parallel}_{eq} = \ell$ at T_q , to an



FIG. 1: The temperatures for which $\chi(\tau)$ peaks are extracted from the plots of $\chi(\tau)$ versus temperature at different observation times τ , where $\tau = \omega^{-1}$, from Figs. 1(a) in Refs. 10 and 11, for Cu:Mn (13.5 at.%) films of 30 Å and 20 Å, respectively. The points at the higher peak temperatures (shorter τ) are less certain because of the broader experimental curves in this time regime.

equilibrium value [19],

$$\xi_{\rm eq}^{\parallel}(T) = \ell \cdot \left(\frac{T}{T_q}\right)^{-\nu},\tag{8}$$

for $T < T_q$. In the absence of explicit cooling times from Refs. [10, 11], it is impossible to know if $\xi^{\parallel}(t,T)$ had reached its equilibrium value $\xi^{\parallel}_{eq}(T)$ within the time scale of the experiments. For purposes of analysis, we shall assume that sufficient time had elapsed in the experiments of Refs. [10, 11] for $\xi^{\parallel}(t,T)$ to reach $\xi^{\parallel}_{eq}(T)$ as given by Eq. (8). Experiments sensitive to the growth of $\xi^{\parallel}(t,T)$ with time t is an area ripe for further investigation.

From the above arguments, we hypothesize that for decreases in temperature, the increase of $\Delta_{\max}(T)$ arises from an increase in $\Delta_{\max}(T)$ from Eqs. (5) and (6) plus an increase in the Hamming distance [20]. For increases in temperature, our hypothesis is different. The longitudinal correction length is pinned at the film thickness ℓ , effectively pinning the transverse correlation length also at ℓ [19]. The only change of $\Delta_{\max}(T)$ with temperature is through the decrease in the Hamming distance, starting from the value $\Delta_{\max}(T = T_q)$ from Eq. (4).

In principle, the difference in the temperature dependences of $\Delta_{\max}(T)$ for temperatures below and above the quench temperature allows for the extraction of $\xi_{eq}^{\parallel}(T)$, and thus a direct measurement of the d = 2 critical exponent ν from Eq. (8).

We have employed the above analysis to extract $\Delta_{\max}(T)$ from the experiments of Sandlund *et al.* [10] and Granberg *et al.* [11]. Their experiments measured



FIG. 2: The temperature dependent activation energy of the highest barrier, $\Delta_{\max}(T)$ from Eq. (9) for the 30 Å Cu:Mn (13.5 at.%) film, plotted against the peak temperature for $\chi(\tau)$, using the data in Fig. 1. To guide the eye, a best fit to a linear dependence is plotted on the same graph. It is seen that there is a significant departure from a linear relationship between the values of $\Delta_{\max}(T)$ and the peak temperatures for $\chi(\tau)$ at the larger values of $\Delta_{\max}(T)$ (lower peak temperatures).

the temperature dependence of the dynamic susceptibility $\chi(\tau)$ for different observation times τ for thin Cu:Mn (13.5 at. %) films of thicknesses 30 Å and 20 Å, respectively. The observation times $\tau(T)$ ranged over nine and seven orders of magnitude, respectively, in their respective Figs. 1(a). We extract $\Delta_{\max}(T)$ from their measurements through the Arrhenius relation,

$$\frac{1}{\tau(T)} = \frac{1}{\tau_0} \exp\left(-\frac{\Delta_{\max}(T)}{k_B T}\right).$$
 (9)

To extract parameters appropriate to their measurements, we use an average Mn spin separation appropriate to a concentration of 13.5 at. % of $a_0 = 4.45$ Å, and $T_g = 66.8$ K. We make use of the values for c_1 and c_2 for Cu:Mn (6 at. %) extracted by Joh *et al.* [15]: $c_1 = 0.653$ and $c_2 = 0.169$, on the assumption that these parameters are relatively insensitive to Mn concentration. Scaling $1/\tau_0$ from the 6 at. % Mn concentration of Joh *et al.* [15] to the 13.5 at. % Mn concentration of Sandlund *et al.* [10] and Granberg *et al.* [11] leads to $1/\tau_0 = 9.2 \times 10^{12}$ sec⁻¹.

The values for $\Delta_{\max}(T = T_q)$ from Eq. (4) can be extracted through a fit to the data of Refs. [10, 11] for the two film thicknesses using the above parameters. We find $\Delta_{\max}(T = T_q) = 923$ K for $\ell = 30$ Å film, and $\Delta_{\max}(T = T_q) = 727$ K for $\ell = 20$ Å film. As stated above, these values are set by the film thickness, and are independent of temperature. The quench temperatures for these two films were not given in Refs. [10, 11], so we extract them from a fit of Eq. (4) to the peak temperature of the zerofield susceptibility $\chi(\tau)$ for different observation times



FIG. 3: The temperature dependent activation energy of the highest barrier, $\Delta_{\max}(T)$ from Eq. (9) for the 20 Å Cu:Mn (13.5 at.%) film, plotted against the peak temperature for $\chi(\tau)$, using the data in Fig. 1. To guide the eye, a best fit to a linear dependence is plotted on the same graph. Some curvature could be imputed to the experimental points, but the data are too uncertain to claim anything else than a linear relationship between the values of $\Delta_{\max}(T)$ and the peak temperatures for $\chi(\tau)$.

 τ from the data exhibited in Figs. 1(a), respectively, of Refs. [10] and [11]. Fig. 1 plots the temperatures of the peak of the measured $\chi(\tau)$ for each listed value of τ , as best we can extract them from the published figures. We find $T_q = 37.5$ K for the 30 Å film from the data of Ref. [10]; and $T_q = 30$ K for the 20 Å film from Ref. [11].

The temperature dependent $\Delta_{\max}(T)$ can be extracted by applying Eq. (9) to the temperature of the peak of $\chi(\tau)$ for each characteristic time τ , as exhibited in Fig. 1. We plot $\Delta_{\max}(T)$ in Fig. 2 for the 30 Å film, and in Fig. 3 for the 20 Å film. The difference of the dependence of $\Delta_{\max}(T)$ on temperature for the two films is striking. For the 30 Å film, $\Delta_{\max}(T)$ increases more rapidly than linearly with temperature as the temperature is lowered (exhibited by the departure from the "best fit to a linear relationship" line on Fig. 2). For the 20 Å film, the relationship of $\Delta_{\max}(T)$ to temperature is approximately linear (exhibited by the "best fit to a linear relationship" line on Fig. 3).

The data from which we have to work is rather sparse, but taking finite differences from Figs. 2 and 3, we plot the values for $\delta \Delta_{\max}(T)/\delta T$ against $\Delta_{\max}(T)$ for both film thicknesses in Fig. 4. The data for the 30 Å film in Fig. 4(a) is suggestive of a relationship similar to that found for bulk spin glasses [20] in that $-\delta \Delta_{\max}(T)/\delta T$ appears to rise rather rapidly with increasing $\Delta_{\max}(T)$. The solid line is a fit to Eq. (10) below. The data for $\delta \Delta_{\max}(T)/\delta T$ for the 20 Å film in Fig. 4(b) is so scattered that it is difficult to draw any analytic conclusion except that $-\delta \Delta_{\max}(T)/\delta T$ does appear to increase with increasing $\Delta_{\max}(T)$.



FIG. 4: Plots of $\delta \Delta_{\max}(T)/\delta T$ against $\Delta_{\max}(T)$ extracted (a) from the data points for the 30 Å film from Fig. 2 and (b) from the data points for the 20 Å film from Fig. 3. The solid line for the 30 Å film in Fig. 4(a) is a fit of the 30 Å data to an exponential dependence of $\partial \Delta_{\max}(T)/\partial T$ on $\Delta_{\max}(T)$, Eq. 10, following the reasoning of Ref. 20. The scatter for the 20 Å film in Fig. 4(b) obviates any fit.

Following the approach of Ref. 20, we fit the extracted data for $\partial \Delta_{\max}(T)/\partial T$ for the 30 Å film to an exponential form:

$$-\frac{1}{k_B}\frac{\partial\Delta_{\max}(T)}{\partial T} = \alpha \exp\left[\frac{\beta\,\Delta_{\max}(T)}{k_B T_g}\right].\tag{10}$$

In order to reduce the number of unknown constants, we make use of the value $\beta = 0.2$ from Ref. 20. We find $\alpha = 2.18$ from a fit of Eq. (10) to the data in Fig. 4(a). The data exhibit some scatter around the fitted line, with the greatest scatter at the smaller values of $\Delta_{\max}(T)$ that occur at the higher temperatures. The experimental curves for the dynamic susceptibility $\chi(\tau)$ from Fig. 1(a) in [10] are broadest at the higher temperatures, so an accurate extraction of the temperature of the peak is more difficult in this region of temperature [and concomitantly for $\Delta_{\max}(T)$ at the smaller values]. The value of α (2.18) is approximately four times larger than the value of 0.5from [20]. Noting that α in Eq. (10) is a scale factor representing the size of the barrier heights $\Delta(T)$, and that the Mn concentration to which we are fitting for Cu:Mn alloys is 13.5 at.% in Ref. [10], while the Mn concentration of Ref. [20] is 2.6 at.%, one would expect a ratio of approximately five from the concentration difference alone, as compared to four for the increase in α . The closeness of this scaling adds weight to our interpretation.

Integration of Eq. (10) leads to barrier heights increasing ever more rapidly as the temperature is lowered. The



FIG. 5: Integration of the exponential form for the dependence of $\partial \Delta_{\max}(T)/\partial T$ on $\Delta_{\max}(T)$ for 30 Å film, fitted to the experimental data (solid line portion), as a function of $(T - T^*)/T_g$, over the full range of $\Delta_{\max}(T)/(k_B T_g)$ and $(T - T^*)/T_g$ using Eq. 11. The × denotes the value of Δ_{\max} at quench from Eq. 4.

finite thickness of a thin film would mitigate against an infinite barrier height, but the fit in Fig. 4(a) to Eq. (10) certainly suggests much higher barriers for temperatures below those at the lowest experimentally accessible temperature. Integration of Eq. (10) leads to,

$$\frac{\Delta_{\max}(T)}{k_B T_g} = -\frac{1}{\beta} \ln \left[\frac{\alpha \beta \left(T - T^* \right)}{T_g} \right], \text{ for } T > T^*, \quad (11)$$

where in principle $\Delta_{\max}(T)$ would diverge at $T = T^*$.

The fitted values, $\alpha = 2.18$ and $\beta = 0.2$ for the 30 Å film, are used to plot the magnitude of $\Delta_{\max}(T-T^*)$ vs the temperature difference $dT = T - T^*$ from Eq. (11) in Fig. 5. The dashed curve is Eq. (11), with the solid portion the extracted values of $\Delta_{\max}(T)$. The cross is at the position of the quench temperature T_q [equivalently, $\Delta_{\max}(T = T_q)$ from Eq. (4)]. The extrapolated divergence of $\Delta_{\max}(T)$ is predicted to take place at a $(T - T^*)/T_g \approx 0.06$ below the temperature of the lowest peak in [10], 31.5 K, leading to an extrapolated divergence of $\Delta_{\max}(T)$ at $T \approx 27.8$ K. The lowest experimental peak temperature is associated with $\tau = 10^4$ sec. Going to any lower temperature, according to Eq. (11) plotted in Fig. 5, would lead to values of τ well beyond any experimental measurement range for $\chi(\tau)$.

As added evidence, Sandlund *et al.* [10] note that "there is a pronounced cooling rate dependence of the FC susceptibilities, with the knee shifting towards lower temperatures with decreasing cooling rate." Associating the decrease in the cooling rate with an increase in τ is consistent with the growth of $\Delta_{\max}(T)$ as the temperature is lowered. The extrapolated value of $\Delta_{\max}(T)$ would represent an infinite time scale for τ , that would lead to a projected *knee* in the field cooled (FC) magnetic

The results for the 20 Å film are quite different. Fig. 3, the plot of the $\Delta_{\max}(T)$ vs temperature, is approximately linear, displaying no noticeable increase beyond linear at the lower temperatures, and the scatter in Fig. 4(b) is so great that no analytic fit is possible. We suspect the difference of behavior from the 30 Å film is the relatively small number of correlated spins even for times $t > t_{co}$ when $\xi(t_{\rm co}, T_q) = \ell$. With the average distance between Mn spins equal to 4.45 Å, a spherical correlation volume with radius $\ell/2$ would contain only of the order of 50 spins in the 20 Å film, so that one might expect large spatial fluctuations for dynamical properties. This could be the origin of the scatter in Fig. 4(b). The 30 Å film contains of the order of 160 spins within a correlation volume at $t = t_{co} [\xi(t = t_{co}, T_q) = \ell]$ and can be thought of as a precursor to bulk. It would be of interest to probe the dynamical properties of films with thicknesses in the vicinity of 20 Å to 30 Å to probe the approach to bulk behavior as a function of the number of correlated spins.

It should be noted that the interpretations of Refs. [10] and [11] differ from our own, in that they associate their observed time scales with a generalized Arrhenius law using droplet scaling theory [33] for two-dimensional spinglass systems. Their analysis, on the assumption of a zero temperature transition (Eq. 3 of Ref. [10]), is based on,

$$\ln(\tau/\tau_0) \propto T_f^{-(1+\psi\nu)},\tag{12}$$

with T_f their "freezing temperature" associated with the maximum in the time-dependent susceptibility, and $\psi\nu = 1.6 \pm 0.2$. Our own analysis would yield a form more like that for critical dynamics [20]. Inserting (11) into (9), we find,

$$\frac{\tau}{\tau_0} = \alpha \beta \left(\frac{T - T^*}{T_g}\right)^{-1/[\beta \cdot (T/T_g)]}.$$
(13)

This expression is of the usual critical exponent form [34], with $z\nu = 1/[\beta \cdot (T/T_g)]$. Using our value for $\beta = 0.20$, and taking T equal to the quench temperature 37.5 K, we find $z\nu \approx 9$. Further, from Fig. 5, we find a value for $T^* = 27.8$ K. The former is in rather remarkable agreement with experiments on three dimensional spin glasses [35, 36], and the latter with the value extracted using a critical slowing down analysis in [10] of $T_g = 26$ K.

Our analysis, based spin glass correlations after $\xi(t, T)$ has reached the film thickness ℓ , appears consistent with all known relevant thin film and bulk experimental data.

IV. ORIGIN OF THE LOGARITHMIC TIME DEPENDENCE FOR TRM DECAY

In a polycrystalline sample, there is a distribution of crystallite sizes. As argued in the Introduction, this will introduce scattering into the integral responsible for the RKKY interaction, the oscillatory character of which is responsible for frustration that leads to spin glass behavior in dilute magnetic systems. The scatter changes the long range oscillations to a uniform coupling falling off faster than the RKKY interaction [24]. This removes frustration and effectively decouples the spin glass states in the grains from one another, even though the electrical conductivity remains high.

The distribution of crystallite sizes, and hence of length scales ℓ , introduces dynamics that are more complex than for the uniform thin films treated in Sec. III. We denote the distribution of crystallite sizes through a probability distribution $\mathcal{P}(\ell)$, where ℓ is the length scale associated with a given crystallite. There exists, therefore, a maximum barrier height $\Delta_{\max}(T = T_q)$ associated with each crystallite of length scale ℓ from Eq. (4), that we designate as $\Delta_{\max}(\ell)$. All of the experiments treated in this section will be at constant measuring temperature T_q , so that Eq. (4) uniquely determines $\Delta_{\max}(\ell)$.

The distribution of length scales ℓ , governed by a probability density $\mathcal{P}(\ell)$, leads from (4) to a probability density for $\Delta_{\max}(\ell)$ given by,

$$\mathcal{P}(\Delta_{\max}) = [\partial \Delta_{\max}(\ell) / \partial \ell]^{-1} \mathcal{P}(\ell).$$
(14)

The purpose of this Section is to derive the long time dynamical properties for a polycrystalline spin glass. An example is the work of Kenning *et al.* [27] who displayed a logarithmic time dependence for the decay of the thermoremanent magnetization, $M_{\text{TRM}}(t, T_q)$ at long decay times. We shall derive this property on the assumption that the measurement time scale is sufficiently long that each crystallite has crossed over into a low dimensional state. That is, we assume that for each crystallite there is a crossover time t_{co}^{ℓ} , defined by $\xi(t_{co}^{\ell}, T_q) = \ell$, and that the measurement time $t > t_{co}^{\ell}$, for all ℓ .

The time development of $M_{\text{TRM}}(t,T)$ can then be deduced as follows. Upon removal of the magnetic field, all barriers are reduced in height by the change in Zeeman energy, E_Z [37] (see the next section for more detail). The states occupied between barriers from $0 < \Delta < E_Z$ are instantaneously emptied into the lowest energy Zeeman state (in our case, M = 0 for TRM decay). The remaining states then decay to the M = 0 state by transitions over the remaining barriers of height $0 < \Delta <$ $\Delta_{\max}(\ell) - E_Z$. For small changes in magnetic field, we can neglect E_Z with respect to $\Delta_{\max}(\ell)$, so that the effective decay rate for a particle of size ℓ will be set by the largest barrier $\Delta_{\max}(\ell)$. For waiting times short compared to the time for $\xi(t, T_q)$ to reach ℓ (we shall see that this condition is violated in some cases in Sec. VI), as the measurement time t increases, the TRM decay will cross over from conventional TRM decay to exponential for a given particle of length scale ℓ at measurement times $t > t_{\rm co}^{\ell}$. We shall refer to the magnetization remaining at that time in the particle of length scale ℓ as $M_{\text{TRM}}^{\ell}(t > t_{\text{co}}^{\ell}, T_q)$. This leads to a size-dependent decay rate $1/\tau_{\ell}$ for $M_{\text{TRM}}^{\ell}(t > t_{\text{co}}^{\ell}, T_q)$ for a particular crystallite of length scale ℓ , where by generalizing Eq. (9),

$$\frac{1}{\tau_{\ell}} = \left(\frac{1}{\tau_0}\right) \exp\left[-\frac{\Delta_{\max}(\ell)}{k_B T_q}\right].$$
(15)

For a particle of length scale ℓ , $M_{\text{TRM}}^{\ell}(t > t_{\text{co}}^{\ell}, T_q)$ will then decay according to,

$$M_{\rm TRM}^{\ell}(t > t_{\rm co}^{\ell}, T_q) = M_{\rm TRM}^{\ell}(t_{\rm co}^{\ell}, T_q) \exp(-t/\tau_{\ell}).$$
(16)

A polycrystalline sample consists of particles of length scale ℓ distributed through a probability density $\mathcal{P}(\ell)$. This requires that (16) with (15) be averaged over $\mathcal{P}(\ell)$. To make the average tractable, we shall replace $M_{\text{TRM}}^{\ell}(t_{\text{co}}^{\ell}, T_q)$ with an average $M_{\text{TRM}}(t_{\text{co}}, T_q)$ that will have to be extracted from experiment. We are then left with integrals of the sort

$$\int_0^\infty \exp(-t/\tau_\ell) \,\mathcal{P}(\ell) \,d\ell. \tag{17}$$

To make the evaluation more transparent, we use (14) with (15) to transform from $\mathcal{P}(\ell)$ to $\mathcal{P}(\Delta)$. The integrals are then of the form, in an obvious notation,

$$\int_0^\infty \exp(-t/\tau_\Delta) \,\mathcal{P}(\Delta) \,d\Delta. \tag{18}$$

This class of integrals were first evaluated in this context by Ma [25]. For a flat distribution of barrier heights of width much greater than $k_B T_q$, (18) can be transformed to,

$$\int_{k_B T_q \ln(t/\tau_0)}^{\infty} \mathcal{P}(\Delta) \, d\Delta. \tag{19}$$

We take $\mathcal{P}(\Delta)$ to be flat with width \mathcal{D} between $\Delta_0 - (\mathcal{D}/2)$ and $\Delta_0 + (\mathcal{D}/2)$, where Δ_0 is the mean value of Δ in $\mathcal{P}(\Delta)$, and we assume $\mathcal{D} \gg k_B T_q$, so that $\mathcal{P}(\Delta) = 1/\mathcal{D}$. Ma [25] evaluates this integral by noting that it is the area under $\mathcal{P}(\Delta)$ to the right of $(T_q/T_g) \ln(t/\tau_0)$. The part to the left of $(T_q/T_g) \ln(t/\tau_0)$ has already decayed. Then the integral (19) is equal to,

$$\frac{1}{\mathcal{D}} \left[\Delta_0 + \frac{\mathcal{D}}{2} - k_B T_q \, \ln\left(\frac{t}{\tau_0}\right) \right]. \tag{20}$$

Using (16) and (20), we now have,

$$M_{\text{TRM}}(t, T_q) = \frac{M_{\text{TRM}}(t_{\text{co}}, T_q)}{\mathcal{D}} \left[\Delta_0 + \frac{\mathcal{D}}{2} - k_B T_q \ln\left(\frac{t}{\tau_0}\right) \right], \quad (21)$$

where $t > t_{co}^{\ell}$ for all ℓ . Taking the derivative with respect to $\ln t$ generates,

$$\frac{\partial M_{\rm TRM}(t, T_q)}{\partial \ln t} = -\mathcal{B} T_q^{(r)} M_{\rm TRM}(t_{\rm co}, T_q), \qquad (22)$$

where \mathcal{B} is a constant containing the many factors associated with (22), $T_q^{(r)} = T_q/T_g$, and $M_{\text{TRM}}(t_{\text{co}}, T_q)$ is



FIG. 6: Reproduction of Fig. 1 from Ref. 27. Fig. 6(a) are the decay curves for t_w^{eff} equal to 7, 17.5, 25, 27, 35, 44, and 110 sec. In the inset, the relaxation curves S(t) for each curve are used to determine t_w^{eff} . Fig. 6(b) displays the subtraction of the $t_w^{eff} = 7$ sec TRM decay curve from the other TRM curves. The $M_{\text{TRM}}(t)$ curve for $t_w^{eff} = 17.5$ sec begins to overlap the $M_{\text{TRM}}(t)$ curve for $t_w^{eff} = 7$ sec at a time $t_{\text{ov}} \approx 6000$ sec, while the curve for $t_w^{eff} = 44$ sec overlaps at a $t_{\text{ov}} \sim 10^5$ sec, and by extrapolation the curve for $t_w^{eff} = 110$ sec overlaps at a time $t_{\text{ov}} \sim 10^9$ sec. The inset displays the relaxation curve S(t) for the $t_w^{eff} = 7$ sec curve, The curve becomes horizontal at $t \sim 10^3$ sec, remaining flat over two orders of magnitude in time, indicating a crossover to a logarithmic time dependence for the decay of $M_{\text{TRM}}(t)$.

an average value of $M_{\text{TRM}}(t, T_q)$ over the various times t_{co}^{ℓ} (equivalently, an average of $M_{\text{TRM}}^{\ell}(t_{\text{co}}^{\ell}, T_q)$ over particle dimensions ℓ). Experimentally, $M_{\text{TRM}}(t_{\text{co}}, T_q)$ will be taken to be the value of the TRM when the decay crosses over to $\ln t$ behavior.

The experimental data for S(t) for Cu:Mn (6 at. %), at $T_q = 26$ K $[T_q^{(r)} = 0.83]$, was reported in Ref. [27] and their Fig. 1 is reproduced here as our Fig. 6. The inset in Fig. 6(b) for the shortest effective waiting time (7 sec) clearly displays a crossover to logarithmic behavior at approximately 1,000 sec, and continues for at least two orders of magnitude in time. Using the parameters from Joh *et al.* [3], one can calculate the value of the correlation length $\xi(t, T_q)$ to test the assumptions leading to Eq. (15). At $t = 10^3 \sec{\xi(10^3, 26 \text{ K})} \approx 60 \text{ nm}$. At $t = 10^5 \sec{\xi(10^5, 26 \text{ K})} \approx 130 \text{ nm}$. Rodriguez *et al.* [2] estimate crystallite sizes ranging from 80 nm to 300 nm, with an average size of approximately 100 nm. Thus, in the time regime contained in the inset of Fig. 6(b), where logarithmic time behavior is exhibited, the correlation length is comparable to the length scale of the Cu:Mn crystallites, a condition required for the use of Eq. (15) for $1/\tau_{\ell}$. The broad range of crystallite length scales probed by $\xi(t,T)$ over this time scale is consistent with the approximations contained in the evaluation of Eq. (19).

It should be noted that logarithmic behavior at long times is not limited to spin glasses. For example, Amir *et al.* [26] find a rather "general mechanism for slow relaxations and aging, which predicts logarithmic relaxations ...", and, in an extensive analysis of electron glass dynamics, find many examples of $\ln t$ behavior. In that sense Eq. (22) may be a specific manifestation of a more general relationship for glassy systems.

V. VERY LONG TIME BEHAVIOR OF $\mathbf{M_{TRM}(t,T)}$

The previous section discussed the long time behavior for polycrystalline spin glasses after crossover to d < 3, i.e. when the correlation length has reached the length scale of the crystallites. Fig. 6(b) (reproduced from Fig. 1(b) of [27]) exhibits the subtraction of the $t_w^{eff} = 7$ sec TRM decay curve for the fast cooling protocol from those at longer effective waiting times, $17.5 \le t_w^{eff} \le 44$ sec, all utilizing the fast cooling protocol, for polycrystalline Cu:Mn (6 at.%). The striking feature of these differences is the very long time for the various curves to crossover to the $t_w^{eff} = 7$ sec value. For example, the long time portion of the $t_w^{eff} = 17.5$ sec decay curve overlaps the long time portion of the $t_w^{eff} = 7$ sec decay curve at an overlap time, t_{ov} , of $\approx 6,000$ sec, whereas the $t_w^{eff} = 44$ sec and the $t_w^{eff} = 110$ sec curves do not overlap at long times with the $t_w^{eff} = 7$ sec decay curve until $t_{ov} \sim 10^5$ sec and, by inference, 10^9 sec, respectively.

We suggest that this striking dependence of the long time behavior of the TRM decay upon t_w^{eff} is the result of the dependence of the initial magnitude of $M_{\text{TRM}}(t_{\text{ov}}, T_q = 0.83 T_g)$ on the effective waiting time, t_w^{eff} . The highest barrier surmounted during a waiting time t_w^{eff} is given by Eq. (9) that we rewrite as,

$$\Delta(t_w^{eff}, T_q) = k_B T_q (\ln t_w^{eff} - \ln \tau_0). \tag{23}$$

When the magnetic field is removed, measurements by Chu *et al.* [36], along with other observations of a similar nature by Vincent *et al.* [37], suggest that a change in magnetic field *reduces* the barriers in the initially occupied field cooled magnetization manifold, $M_{\rm FC}$, by the change in Zeeman energy E_Z . This reduction can be thought of conceptually as diffusion between states of constant $M_{\rm FC}$ through intermediate states of lower Zeeman energy [38]. States within the $M_{\rm FC}$ manifold with barriers less than the Zeeman energy change are emptied



FIG. 7: A logarithmic plot of the time for the $M_{\text{TRM}}(t)$ curves to overlap the $M_{\text{TRM}}(t)$ curve for $t_w^{eff} = 7$ sec, as a function of their respective t_w^{eff} .

instantaneously into the M = 0 manifold [35, 36]. The Zeeman energy change is given by,

$$E_Z = N_s \,\chi_{\rm FC} \,H^2, \tag{24}$$

where N_s is the number of spins within a correlation length that participate in barrier hopping (we shall set $N_s = [\xi(t_w^{eff}, T_q)/a_0]^3)$, and $\chi_{\rm FC}$ is the magnetic susceptibility per spin obtained from the total value of the field cooled magnetic susceptibility $M_{\rm FC}/H$ divided by the total number of spins N.

From Eqs. (23) and (24), the larger t_w^{eff} , the larger the thermoremanent magnetization, $M_{\text{TRM}}(t = 0, T_q)$, remaining when the magnetic field is removed. That is, the fractional change $E_Z/\Delta(t_w^{eff}, T_q)$ diminishes as t_w^{eff} increases. This is seen explicitly in Fig. 6 where the initial value of $M_{\text{TRM}}(t = 0, T_q = 0.83 T_g)$ increases as t_w^{eff} increases. Hence, in order for the long time decay portions of $M_{\text{TRM}}(t, T_q)$ to become comparable in magnitude for differing values of t_w^{eff} , the offset in the initial values of $M_{\text{TRM}}(t=0,T)$ must be overcome through the time decay of $M_{\text{TRM}}(t, T_q)$. But the very slow decay of $M_{\rm TRM}(t,T_q)$ for $t > t_{\rm co}$, proportional to $\ln(t/\tau_0)$ from (21), means that this difference will take very long times, exponentially increasing with increasing t_w^{eff} . This dependence is exhibited in Fig. 7 where $t_{\rm ov}$ is plotted against t_w^{eff} .

VI. EFFECTIVE WAITING TIME DEPENDENCE OF t_{co}

It was pointed in the Introduction that the crossover time to logarithmic time decay for $M_{\text{TRM}}(t, T_q)$ depends on the effective waiting time, t_w^{eff} . This is caused by the growth of $\xi(t, T)$ during the waiting time. If, for example, $\xi(t, T)$ were to grow during t_w^{eff} to overlap some 10

of the smaller crystallites, then when the magnetic field is removed, the smaller crystallites portion of $\mathcal{P}(\ell)$ (i.e. those with the smallest length scale ℓ) would have already have transitioned to d < 3. Then, as time progresses after removal of the magnetic field, it would appear that the mean of $\mathcal{P}(\ell)$ for which aging continues (i.e. for d = 3 dynamics) is shifted to larger ℓ . This would show up as an increase of $t_{\rm co}$ with increasing t_w^{eff} . It would be interesting to test this dependence experimentally. For example, in the Cu:Mn 6% sample used in the experiments of Rodriguez *et al.* [2], at $T_q/T_g = 0.95$, a waiting time of $t_w = 110$ sec would yield $\xi(t_w = 110 \text{ sec}, T_q = 0.95 T_g) = 86 \text{ nm}$, just overlapping the smallest of the crystallites in his sample. For $t_w = 406 \text{ sec}, \ \xi(t_w = 406 \text{ sec}, T_q = 0.95 T_g) = 106 \text{ nm}, \text{ al-}$ ready larger than the mean crystallite size of his sample. Thus, the system would contain effectively larger crystallites for cross over to logarithmic decay with increasing t_w^{eff} , hence a larger t_{co} for larger t_w^{eff} . Experiments remain to be performed over accessible time scales to check this prediction.

VII. SUMMARY

We have explored the dynamics for spin glasses at the mesoscale. For uniform thin films, we have exhibited how the crossover from d = 3 to d = 2 results in spin glass correlations with the perpendicular correlation length equaling the film thickness, while the parallel correlation length grows as the temperature is lowered. The ultrametric nature of these states generates a temperature dependence of the dynamics, consistent with the observed temperature dependence of the dynamic susceptibility $\chi(\tau)$ for a thin film of Cu:Mn (13.5 at.%) of thickness 30 Å [10]. We were unable to analyze the dynamics of the thinner film of thickness 20 Å [11] because of what we believe to be large spatial fluctuations associated with the relatively small number of spins within a correlated volume. For polycrystalline samples, we have derived an expression for the logarithmic decay of the TRM after the correlation length has become comparable to crystallite sizes. This behavior is nearly universal for glassy systems [28, 29], and in this sense, spin glasses follow suit. The time for $\xi(t, T)$ to become comparable to crystallite dimensions falls within the experimentally accessible range for temperatures in the vicinity of T_q , but increases precipitously with lower temperatures. Finally, predictions are made with respect to the onset of the logarithmic decay of the thermoremanent magnetization (TRM) that should be explored.

VIII. ACKNOWLEDGMENTS

The authors wish to acknowledge conversations with Drs. G.A. Henkelman, D.E. Makarov and P.J. Rossky, an extensive discussion with Dr. D.R. Reichman, and detailed correspondence with Dr. F. Ritort. The authors are also indebted to Dr. M.A. Moore who first pointed out the importance of the growth of the parallel correlation length, and to Dr. A. P. Young for many discussions concerning spin glass dynamics in d = 2, and for the explicit expression for the parallel correlation length exhibited in Eq. (8). This research was supported in part by the Cockrell Family Regents Chair in Engineering #12, and the Cockrell Family Dean's Chair in Engineering Excellence, both at The University of Texas at Austin. The authors also wish to thank Dr. Sanjay K. Banerjee, NRI SWAN, and NSF NNIN for their support of this research.

IX. BIBLIOGRAPHY

[1] V.S. Zotev, G.F. Rodriguez, G.G. Kenning, R. Orbach, E. Vincent and J. Hammann, Phys. Rev. B 67, 184422 (2003).

[2] G.F. Rodriguez, "Initial Conditions and Long Time Dynamics for a Complex System: Hierarchical properties of the Spin Glass Decay", Thesis, U. Calif. Riverside, unpublished (2004); G.F. Rodriguez, G.G. Kenning and R. Orbach, Phys. Rev. B 88, 054302 (2013).

[3] Y.G. Joh, R. Orbach, G.G. Wood, J. Hammann and E. Vincent, J. Phys. Soc. Jpn. **69**, Suppl. A, 215 (2000).
[4] S. Guchhait and R. Orbach, Phys. Rev. Lett. **112**, 126401 (2014).

[5] S. Franz, G. Parisi, and M.A. Virasoro, J. Phys. I (France) 4, 1657 (1994).

[6] L.W. Lee and A.P. Young, Phys. Rev. B 76, 024405 (2007).

[7] "From Quanta to the Continuum: Opportunities for Mesoscale Science," A Report from the Basic Energy Sciences Advisory Committee, Chr. G. Crabtree and J. Sarrao, Office of Science, U.S. Department of Energy, 2012.
[8] G.G. Kenning, J.M. Slaughter, and J.A. Cowan, Phys. Rev. Lett. 59, 2596 (1987).

[9] G.G. Kenning, J. Bass, W.P. Pratt, Jr., D. Leslie-Pelecky, L. Hoines, W. Leach, M.L. Wilson, R. Stubi, and J.A. Cowan, Phys. Rev. B **42**, 2393 (1990).

[10] L. Sandlund, P. Granberg, L. Lundgren, P. Nordblad, P. Svedlindh, J.A. Cowan, and G.G. Kenning, Phys. Rev. B 40, 869 (1989).

[11] P. Granberg, P. Nordblad, P. Svedelindh, L. Lundgren, R. Stubi, G.G. Kenning, D.L. Leslie-Pelecky, J. Bass, and J. Cowan, J. Appl. Phys. **67**. 5252 (1990).

[12] E. Marinari, G. Parisi, J. Ruiz-Lorenzo, and F. Ritort, Phys. Rev. Lett. **76**, 843 (1996).

[13] J. Kisker, L. Santen, M. Schreckenberg, and H. Rieger, Phys. Rev. B **53** 6418 (1996).

[14] P. Sibani, C. Shón, P. Salamon, and J.-O. Andersson,
Europhys. Lett. 22, 479 (1993); P. Sabani and J.-O
Andersson, Physica (Amsterdam) 206A, 1 (1994).

[15] T. Shirakura and S. Inawashiro, J. Phys.: Condens. Matter **3**, 3785 (1991); Y.G. Joh, R. Orbach, G.G. Wood, J. Hammann, and E. Vincent, Phys. Rev. Lett. **82**, 438 (1999). [16] H. Rieger, J. Phys. A26, L615 (1993); H. Rieger, B.
 Steckemetz, and M. Schreckenberg, Europhys. Lett. 27, 485 (1994).

[17] H. Rieger, L. Santen, U. Blasum, M. Diehl, M. Jünger, and G. Rinaldi, J. Phys. A: Math. Gen. 29, 3939 (1996).

[18] H. Kawamura and H. Yonehara, J. Phys. A: Math. Gen. 36, 10867 (2003).

[19] A.P. Young, private communication.

[20] Ph. Refregier, E. Vincent, J. Hammann, and M. Ocio, J. Physique I (France) 48 1533 (1987); M. Lederman, R. Orbach, J. Hammann, M. Ocio and E. Vincent, Phys. Rev. B44, 7403 (1991); J. Hammann, M. Lederman, M. Ocio, R. Orbach and E. Vincent, Physica 185A, 278 (1992). Anticipation of an *effective* non-ergodicity that preserves the heirarchy of free energy valleys, but allows transitions, was proposed by S.L. Ginzburg, Sov. Phys. JETP 63, 439 (1986).

[21] M. Mèzard, G. Parisi, N. Sourlas, G. Toulouse, and
 M.A. Virasoro, Phys. Rev. Lett. 52, 1156 (1984); *ibid* J. Physique 45, 843 (1984).

[22] D. Vertechi and M.A. Virasoro, J. Physique I (France) 50, 2325 (1989).

[23] S. Guchhait, M. Jamil, H. Ohldag, A. Mehta, E. Arenholz, G. Lian, A. LiFatou, D. A. Ferrer, J. T. Markert, L. Colombo, and S. K. Banerjee, Phys. Rev. B 84, 024432 (2011).

[24] T. Kasuya, "s-d and s-f Interaction and Rare Earth Metals," *Magnetism*, Vol. IIB, Ed. by G.T. Rado and H. Suhl (Academic Press, New York, 1966), pp. 215 - 294.
[25] Shang-keng Ma, Phys. Rev. B22, 4484 (1980).

[26] A. Amir, Y. Oreg, and Y. Imry, Ann. Rev. Cond. Mat. Phys. 2, 235 (2011); *ibid* Proc. Nat. Acad. Sci. 109, 1850 (2012).

[27] G.G. Kenning, G.F. Rodriguez and R. Orbach, Phys. Rev. Lett. 97, 057201 (2006).

[28] A.L. Burin, D. Natelson, D.D. Osheroff and Y. Kagan, "Tunneling Systems in Amorphous and Crystalline Solids," Ed. by P. Esquinazi (Springer, Berlin, 1998), pp. 223 - 316.

[29] P. Nalbach, D.D. Osheroff and S. Ludwig, J. Low Temp. Phys. **137**, 395 (2004).

[30] D. Parker, F. Ladieu, J. Hammann and E. Vincent, Phys. Rev. B74, 184432 (2006).

[31] P. Nordblad, P. Svedlindh, L. Sandlund and L. Lundgren, Phys. Lett. A120, 475 (1987).

[32] G. Parisi, Phys. Lett. A 73, 203 (1979); Phys. Rev.
 Lett. 43, 1574 (1979); J. Phys. A 13, L-463 (1980).

[33] D.S. Fisher and D.A. Huse, Phys. Rev. B **38**, 373 (1988); **38**, 386 (1988); **36**, 8937 (1987).

[34] K. Gunnarsson, P. Svedlindh, P. Nordblad, L. Lundgren, H. Aruga, and A. Ito, Phys. Rev. Lett. **61**, 754 (1988)

[35] P. Svedlindh, L. Lundgren, P. Nordblad, and H.S. Chen, Europhys. Lett. 3, 243 (1987); P. Nordblad,
L. Lundgren, P. Svedlindh, K. Gunnarsson, H. Aruga and A. Ito, J. Phys. (Paris) Colloq. (France) 49, C8-1069 (1988); S.M. Rezende, F.C. Montenegro, M.D.

Coutinho-Filho, C.C. Becerra, and A. Paduan-Filho, J. Phys. (Paris) Colloq. **49**, C8-1267 (1988); L. Lèvy, Phys. Rev. B **38**, 4963 (1988); E. Vincent, J. Hammann, and M. Alba, Solid State commun. **58**, 57 (1986); N. Bontemps, J. Rajchenbach, R.V. Chamberlin, and R. Orbach, Phys. Rev. B **30**, 6514 (1984).

[36] D. Chu, G.G. Kenning, and R. Orbach, Phil. Mag. B71, 4790 (1995); D. Chu, thesis, University of California, Los Angeles, 1994, unpublished.

[37] E. Vincent, J.-P. Bouchaud, D.S. Dean, and J. Hammann, Phys. Rev. B 52, 1050 (1995); Y.G. Joh, R. Orbach, and J. Hammann, Phys. Rev. Lett. 77, 4648 (1996); Philos. Mag. B 77, 231 (1998).

[38] J.-P. Bouchaud, J. Phys. (France) I 2, 1705 (1992);
J.-P. Bouchaud and D.S. Dean, J. Phys. I (France) 5, 265 (1995);
E. Vincent, J.-P. Bouchaud, D.S. Dean, and J. Hammann, Phys. Rev. B 52, 1050 (1995).